74HC3G04; 74HCT3G04

Inverter

Rev. 4 — 2 October 2013

Product data sheet

1. General description

The 74HC3G04; 74HCT3G04 is a triple inverter. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - ◆ For 74HC3G04: CMOS level
 - ◆ For 74HCT3G04: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
 - ♦ HBM JESD22-A114E exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74HC3G04DP	-40 °C to +125 °C	TSSOP8	· · · · · · · · · · · · · · · · ·						
74HCT3G04DP			body width 3 mm; lead length 0.5 mm						
74HC3G04DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads;	SOT765-1					
74HCT3G04DC			body width 2.3 mm						
74HC3G04GD	–40 °C to +125 °C	XSON8	SON8 plastic extremely thin small outline package; no leads;						
74HCT3G04GD			8 terminals; body $3 \times 2 \times 0.5$ mm						



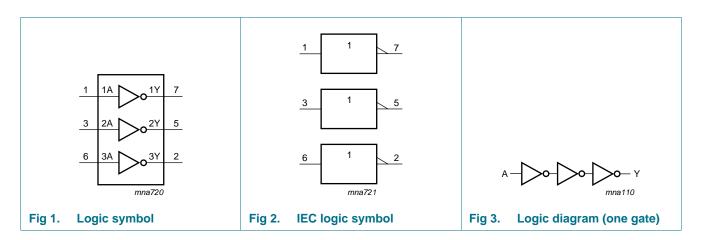
4. Marking

Table 2. Marking codes

•	
Type number	Marking code ^[1]
74HC3G04DP	H04
74HCT3G04DP	T04
74HC3G04DC	H04
74HCT3G04DC	T04
74HC3G04GD	H04
74HCT3G04GD	T04

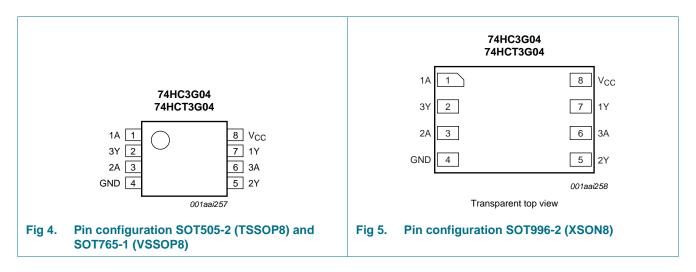
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



74HC_HCT3G04

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6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
GND	4	ground (0 V)
1Y, 2Y, 3Y	7, 5, 2	data output
V_{CC}	8	supply voltage

7. Functional description

Table 4. Function table[1]

Input	Output
nA	nY
L	Н
Н	L

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	<u>[1]</u> _	25	mA
I _{CC}	supply current		<u>[1]</u> _	50	mA
I_{GND}	ground current		<u>[1]</u> –50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P_D	dynamic power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	<u>[2]</u> _	300	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K. For XSON8 package: above 45 °C the value of P_{tot} derates linearly with 2.4 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	7	4HC3G0	4	74HCT3G04			Unit
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
an	and fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C 1	to +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC3G	04		'		'	1	1	1		
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	8.0	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
OU		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	4.13	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.68	5.81	-	5.63	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A$; $V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$; $V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	per input pin; $V_{CC} = 6.0 \text{ V}$; $V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}$;	-	-	1.0	-	10	-	20	μА

 Table 7.
 Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
C _I	input capacitance		-	1.5	-	-	-	-	-	pF
74HCT3	G04									
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	8.0	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	4.13	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	per input pin; $V_{CC} = 5.5 \text{ V}$; $V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}$;	-	-	1.0	-	10	-	20	μА
ΔI_{CC}	additional supply current	per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} - 2.1 \text{ V}; I_{O} = 0 \text{ A}$	-	-	300	-	375	-	410	μΑ
Cı	input capacitance		-	1.5	-	-	-	-	-	pF

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); all typical values are measured at T_{amb} = 25 °C; for test circuit see Figure 7.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
74HC3G	04						1		1	1	
t _{pd}	propagation	nA to nY; see Figure 6	<u>[1]</u>								
	delay	$V_{CC} = 2.0 \text{ V}$		-	22	75	-	90	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	8	15	-	18	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	20	ns
t _t	transition	see Figure 6	[2]								
	time	V _{CC} = 2.0 V		-	18	75	-	95	-	125	ns
		V _{CC} = 4.5 V		-	6	15	-	19	-	25	ns
		$V_{CC} = 6.0 \text{ V}$		-	5	13	-	16	-	20	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$	[3]	-	9	-	-	-	-	-	pF

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); all typical values are measured at T_{amb} = 25 °C; for test circuit see Figure 7.

Symbol Parameter		Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
74HCT3G04											
t _{pd}		nA to nY; see Figure 6	[1]								
	delay	V _{CC} = 4.5 V		-	10	18	-	23	-	29	ns
t _t	transition time	$V_{CC} = 4.5 \text{ V}$; see Figure 6	[2]	-	6	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$	[3]	-	9	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_t is the same as t_{TLH} and t_{THL} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

12. Waveforms

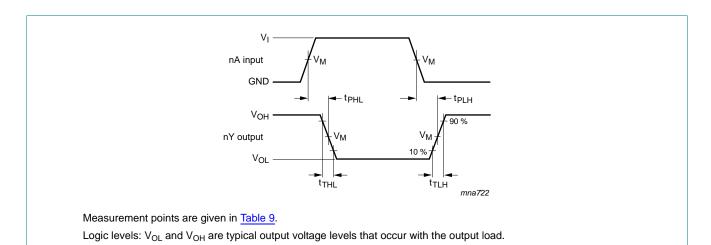


Table 9. Measurement points

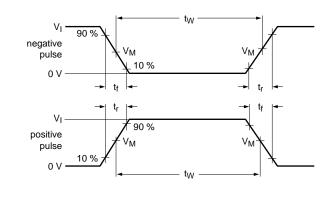
The data input (nA) to output (nY) propagation delays

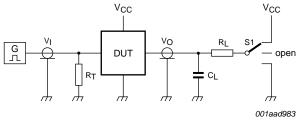
rabio or incacaroment p								
Туре	Input	Output						
	V _M	V _M						
74HC3G04	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$						
74HCT3G04	1.3 V	1.3 V						

74HC_HCT3G04

Fig 6.

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Test data is given in Table 10.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

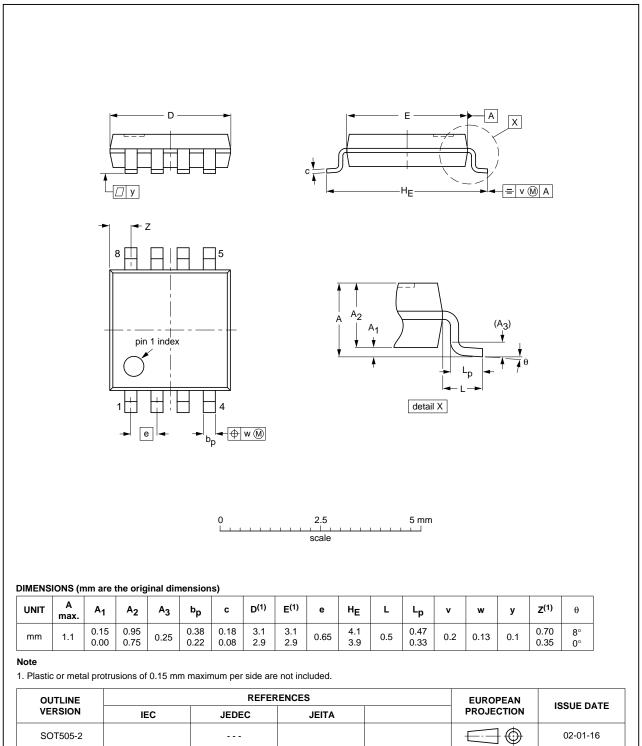
Fig 7. Load circuit for measuring switching times

Table 10. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}
74HC3G04	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open
74HCT3G04	3 V	≤ 6 ns	50 pF	1 kΩ	open

13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT505-2						02-01-16

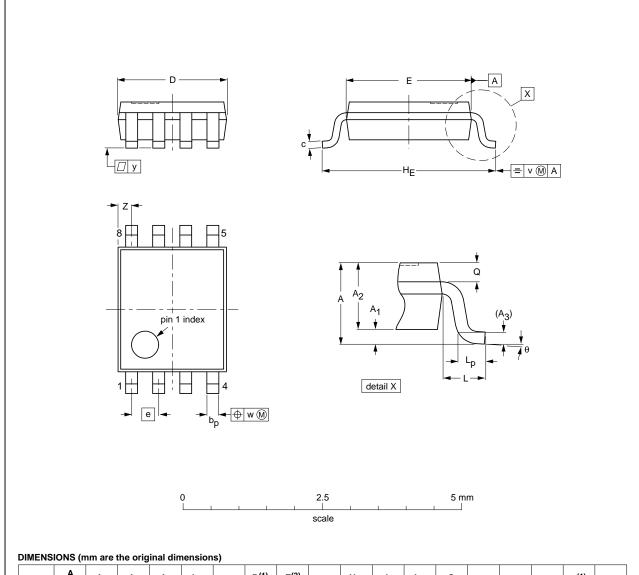
Package outline SOT505-2 (TSSOP8) Fig 8.

74HC_HCT3G04

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VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

Notes

- Plastic or metal protrusions of 0.15 mm maximum per side are not included.
 Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT765-1		MO-187				02-06-07

Fig 9. Package outline SOT765-1 (VSSOP8)

74HC_HCT3G04

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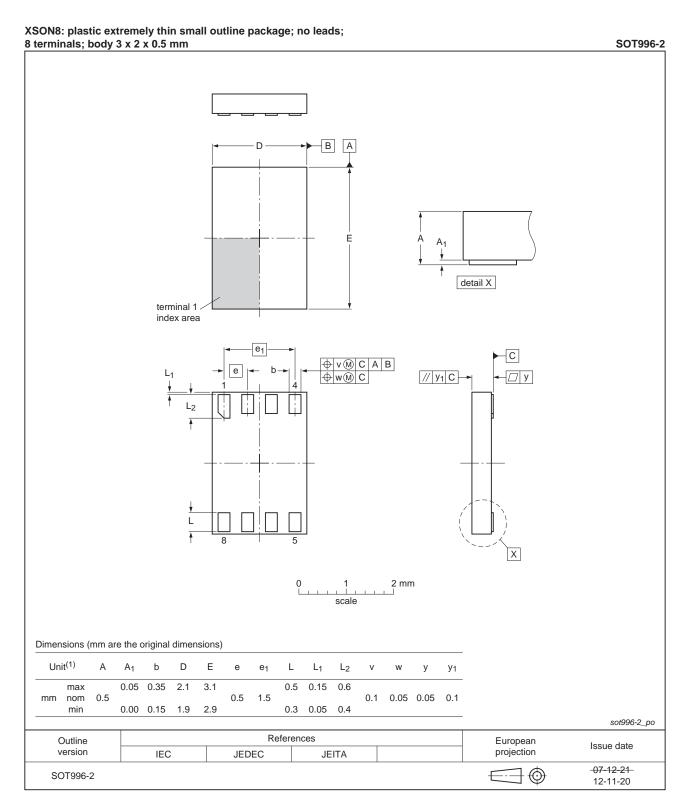


Fig 10. Package outline SOT996-2 (XSON8)

74HC_HCT3G04

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14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 12. Revision history

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT3G04 v.4	20131002	Product data sheet	-	74HC_HCT3G04 v.3
Modifications:	 For type nur 	mbers 74HC3G04GD and 74	HCT3G04GD XSON8	U has changed to XSON8.
74HC_HCT3G04 v.3	20080702	Product data sheet	-	74HC_HCT3G04 v.2
74HC_HCT3G04 v.2	20031030	Product specification	-	74HC_HCT3G04 v.1
74HC_HCT3G04 v.1	20020726	Product specification	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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18. Contents

1	General description
2	Features and benefits
3	Ordering information
4	Marking 2
5	Functional diagram 2
6	Pinning information 2
6.1	Pinning
6.2	Pin description
7	Functional description 3
8	Limiting values 3
9	Recommended operating conditions 4
10	Static characteristics 4
11	Dynamic characteristics 5
12	Waveforms 6
13	Package outline 8
14	Abbreviations11
15	Revision history
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks
17	Contact information
18	Contents

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